Design Considerations of Resonant Network and Transformer Magnetics for High Frequency LLC Resonant Converter

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Abstract – This paper proposes the design considerations of resonant network and transformer magnetics for 500 kHz high switching frequency LLC resonant converter. The high power density can be effectively achieved by adopting high switching frequency which allows small size passive components in the converter. The design methodology of magnetizing inductance is derived for zero voltage switching (ZVS) condition, and the design methodology of the transformer and output capacitance is derived to achieve high power density at high operating frequency. Moreover, the structure of transformer is analyzed to obtain the proper inductance value for high switching operation. To verify the proposed design methodology, simulation and experimental results will be presented including temperature of passive and active components, and power conversion efficiency to evaluate dominant power loss. In addition, the validity of magnetics design will be evaluated with operating waveforms of the prototype converter.

Keywords: High switching frequency, LLC resonant converter, Transformer design, Power density

1. Introduction

These days, a LLC resonant converter is one of the most attractive topologies in the industrial fields such as LED, TV, computer, and other home appliances. It has many advantages of fewer components than other topologies, small circulating current, and low switching losses using soft switching methods such as zero current switching (ZCS) for the secondary side diode, and zero voltage switching (ZVS) for a MOSFET as a main switch over entire load condition [1-10]. Moreover, the LLC converter is good for high frequency switching operation which is one of the latest trends of the switch mode power supply (SMPS). The high frequency switching operation makes the size of passive components small, which increases the power density of the converter. In addition, comparing with conventional hard-switching converters and asymmetrical half-bridge converter, the LLC resonant converter has small switching and conduction losses by the soft switching and the symmetric operation [11-15].

To operate the converter with optimal design in aspect of power density, the design considerations for high switching frequency should be derived. When the switching frequency increases, the size of passive components is proportionally decreasing [16-20]. The relationship between the crosssectional area of the transformer's core and the switching frequency should be investigated to design small-sized transformer properly under high frequency operation.

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Furthermore, the size of output capacitor can be decreased using the relationship among the effective series resistance (ESR), capacitance, and the switching frequency. They can be mathematically induced and be verified with simulation and experimental results.

Meanwhile, the magnetizing inductance should be designed adequately to obtain the ZVS condition, but conventional magnetizing inductance design method has higher error at high frequency operation. Therefore, high frequency magnetics should be considered in the design of the magnetizing inductance at the high switching frequency.

To design the transformer for high frequency switching, several design parameters should be considered. First, a proper size of the magnetic core has to be chosen with considering the saturation limit of the specific flux density. By adjusting the number of turns of the primary winding and the cross-sectional area of the core, proper magnetic core which can avoid the saturation at the switching frequency is selected. Second, the transformer should satisfy required values of the magnetizing inductance and the leakage inductance since the LLC resonant converter uses the inductances as the components of its resonant network. At high switching frequency, the required values of the inductances become smaller. To satisfy the small value of the magnetizing inductance, the structure of the magnetic core should have an air gap. In addition, the winding method should be changed to obtain the small value of the leakage inductance. With respect to all of those parameters, a suitable transformer should be designed to be applied to the LLC resonant converter properly for its high frequency operation.

In this paper, a prototype LLC resonant converter operating at 100 kHz and 500 kHz switching frequency is

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implemented to experimentally verify the validity of the proposed design methodology. To obtain optimal operating points at 100 kHz and 500 kHz switching frequency, the magnetizing inductance is separately designed. The temperature of passive and active components is measured to find out dominant power losses at high frequency operation. In addition, the validity of high-frequency magnetics design is evaluated with mathematical analysis. All the design considerations are verified by proper simulation and experimental results with a 300 W prototype LLC resonant converter operating at 100 kHz and 500 kHz switching frequencies.

2. Design Considerations for Power Stage

The conventional medium switching frequency LLC resonant converter has been designed with the relationship among Q-factor (Quality factor), voltage gain, and λ which is defined as L_r/L_m , where L_r is the leakage inductance and L_m is the magnetizing inductance. The converter which has high λ needs small frequency modulation to control the output voltage since the higher gain variation is introduced by the higher λ . High λ has small conduction losses with small circulating currents, however it has a demerit under over-load condition because of non-monotonic gain curves.

Small λ is convenient to control the output voltage under over-load condition, however, it requires high frequency modulation to obtain enough voltage gain. Moreover, small λ has high conduction loss which comes from high circulating current. The Q-factor changed by load condition shows the sharpness of the voltage gain near the resonant frequency. Fig. 1 shows the scheme of the LLC resonant converter and Fig. 2 shows the voltage gain curve according



Fig. 1. Circuit diagram of the LLC resonant converter



Fig. 2. DC gain characteristics of the LLC resonant converter

to the switching frequency. In this section, design considerations of the resonant network and output capacitance of the LLC resonant converter for high frequency operation will be discussed.

2.1 Design for soft switching condition

To verify the validity of the proposed design methodology, a prototype converter is implemented with an analog controller (ST L6599) which has a fixed dead time (0.2-0.4 μ s). Comparing with the switching frequency of 500 kHz (2 μ s) in the prototype converter, the dead time is longer than 10% of the switching frequency. Fig. 3 shows theoretical waveforms whose dead time from t_c to t_e is large enough to influence the shape of the primary current. The primary current cannot follow the magnetizing current during the dead time, and it is collapsed by the secondary parasitic capacitance before the end of the dead time.

From the above reasons, the conventional design method of the magnetizing inductance is not a proper to obtain the ZVS operation in the high switching frequency operation. Since the conventional design method is derived using the approximation of constant primary current during the dead time, it introduces considerable errors for the ZVS condition. From the conventional design method, the primary current can be expressed as follows:

$$i_{p}(t_{c}) = \frac{n(V_{o} + V_{Df})T_{s}}{4L_{m}}$$
(1)

where t_c is start point of dead time, $i_p(t_c)$ is the constant value of the primary current during the dead time, n is the turn ratio, V_o is the output voltage, V_{Df} is the forward voltage drop of the secondary diode, and T_s is the switching period.

At the high switching frequency, equation (1) cannot be retained during the dead time. Therefore, after t_c , the variation of the primary current during the dead time can be derived as follows:



Fig. 3. Operational waveforms of the primary and the magnetizing current during the dead time

$$i_p(t) = i_p(t_c) \cos \omega_{r1}(t) + \frac{V_b}{Z_{r1}} \sin \omega_{r1}(t)$$
 (2)

where $\omega_{rl} = 2\pi f_{rl}$, $V_b = V_s - V_{cr} - n(V_o + V_{Df})$, V_s is input voltage, f_{rl} is the resonant frequency between the leakage inductance and the resonant capacitor.

The conventional design guide of the magnetizing inductance shown in (3) has high error to obtain the ZVS condition with high dead time ratio.

$$L_m \le \frac{t_{dt}}{16C_s f_{s,\max}} \tag{3}$$

where t_{dt} is the dead time duration, C_s is the parasitic capacitance of primary side MOSFET, and $f_{s,max}$ is the maximum switching frequency.

To obtain proper ZVS condition at the high switching frequency condition, equation (4) is proposed as follows:

$$\frac{V_s t_{dt}}{8L_m} (T_{s,\min} - 2t_{dt}) \ge 2C_s V_s \tag{4}$$

where $T_{s,min}$ is switching period. Eq. (4) considers the current drop during the dead time. Assuming that magnetizing current is linear for the dead time, the current drop can be measured using the average primary current from the start of the dead time (t_c , $T_s/4$) to the end of the dead time (t_e , $T_s/4 - t$). Using (4), a proper design guide of the magnetizing inductance to obtain the ZVS condition at the high switching frequency can be derived as follows:

$$L_m \le \frac{t_{dt}}{16C_s} (T_{s,\min} - 2t_{dt}) \tag{5}$$

Therefore, the magnetizing inductance which guarantee the ZVS of the MOSFET considering the high switching frequency operation with long dead time can be designed.

2.2 Design for smaller output capacitance

At the high switching frequency operation, small-size passive components such as transformer and output capacitor can be used in the converter for high power density. In the case of the output capacitance, the relationship between ESR (effective series resistance) and the output capacitance is important to analyze output voltage ripple as follows:

$$\Delta V = ESR \times (\frac{\pi}{2} - 1) \times I_o + \frac{\Delta Q}{C_o}$$
(6)

where I_o is the output current, T_s is the switching period, and $\Delta Q = 0.363 \times I_o T_s$.

The conventional converter uses high capacitance to reduce the output voltage ripple, but it is not effective



Fig. 4. Ripple voltage variation according to the switching frequency



Fig. 5. Simulation waveform of output ripple voltage: (a) normal ESR, and small capacitance condition; (b) high ESR, and small capacitance condition

method to increase power density, because capacitance is proportional to the size of the capacitor. From (6), the voltage ripple related with the output capacitance is proportional to the output current and inversely proportional to the switching frequency. The voltage ripple from the ESR, however, is only related to the output current.

Fig. 4 shows output voltage ripple variations according to the switching frequency, which is derived from (6). Using Fig. 4 and (6), it is verified that the ESR is dominant factor to reduce the output voltage ripple than output capacitance at the high switching frequency. Therefore, the small ESR, and output capacitance is selected to improve the output voltage ripple, and the power density of the converter at the high frequency operation. The Table 1 and Fig. 5 show three simulation results to verify (6) and Fig. 4.

The case 1, which has normal ESR, and small capacitance condition, shows that capacitance is not dominant to the output voltage ripple at high frequency operation, comparing

| | specification | value | |
|---------------|--------------------------|-------------------------|--|
| Input Voltage | | 420 V | |
| Output | | 30 V/10 A | |
| Case 1 | Output Capacitance (ESR) | 3 μF (15m Ω) | |
| Case 2 | Output Capacitance (ESR) | 3 μF (100m Ω) | |
| | | | |
| Simu | lation Condition | Output Ripple Voltage | |
| Casa 1 | 100 kHz | 5.84 V _{pk pk} | |
| Case 1 | 500 kHz | 1.37 V _{pk pk} | |
| Case 2 | 100 kHz | 6.86 V _{pk pk} | |
| | 500 kHz | 2 81 Val. at | |

 Table 1. Design specifications and simulation results of output ripple voltage

with normal frequency operation. The case 2, which has high ESR, and small capacitance condition, shows that ESR has a high effect on the output voltage ripple at high switching frequency.

3. Design of High Frequency Magnetics

The size of the transformer is determined by the crosssectional area of the core. Eqs. (7) and (8) show the relationship of the cross-sectional area using the faraday's law as follows:

$$V_1(t) = N_p \times \frac{d\Phi}{dt} = N_p \times \frac{d(B \times A_c)}{dt}$$
(7)

$$A_c = \frac{V_1 \times D \times T_s}{\Delta B \times N_p} \tag{8}$$

$$L = L_m + L_{l1} + L_{l2} = \frac{N_p^2}{(R_c + R_g)}$$
(9)

$$A_c = \frac{(D \times \overline{V_1})^2}{\Delta B^2 \times f_s^2 \times L} \times \mu_0 \times \left(\frac{\mu_e}{l_e} + \frac{1}{l_g}\right)$$
(10)

where A_c is the cross-sectional area, $V_I(t)$ is the input voltage, $\overline{V_1}$ is the average value of the input voltage, D is the duty ratio, ΔB is the maximum flux density, N_p is the primary turn number of the transformer, μ_o is the free-space permeability, μ_e is the relative magnetic permeability, R_c is the reluctance of core, R_g is the reluctance of air gap, l_e is the effective magnetic length, and l_g is the air gap length.

As shown in (8), the cross-sectional area is proportional to the input voltage, the duty ratio, and the switching period. It is inversely proportional to the maximum flux density and the primary turn number. In addition, N_p in (8) can be substituted with (9) as shown in (10). In (10), the transformer permeability and the length of the air gap is derived from (8) and its air gap resistance. The size reduction of the transformer and the air gap length is proportional to the square of the switching frequency. Also, the small leakage and magnetizing inductance value at high switching frequency induces large air gap length.



Fig. 6. Theoretical waveform of the input voltage and the flux density in the transformer



Fig. 7. Calculation results of the relation between N_p and $A_{c,min}$ at 500 kHz switching frequency

Assuming that the square of ΔB and $(D \times V_l)$ is constant, the small-sized transformer can be used at 500 kHz switching frequency since $\mu_o(\mu_e l_e^{-1} + l_g^{-1})$ value increases about 2 times and the value of L decreases about 3.5 times. Consequently, the transformer size at 500 kHz switching frequency can be reduced around 3.5 times than the transformer at 100 kHz switching frequency.

3.2 Design parameters for transformer

Since the magnetic flux generated in a magnetic material should be limited before the magnetic core goes into saturation [22], the transformer should be designed to operate within the saturation limit of the flux density. When for the waveforms of the input voltage and the flux density in the transformer are as shown in Fig. 6, the relation of the design parameters from the Faraday's law can be obtained as follows [21, 22]:

$$N_p \ge \frac{V}{\Delta B \cdot A_{\min} \cdot 2f} \tag{11}$$

where N_p is the turn number of the primary winding in the transformer and A_{min} is the smallest cross-sectional area of the magnetic core. The duty-cycle is set by 50% since the core is designed for the LLC resonant converter.

Generally, the conventional ferrite core has a saturation flux density of around 0.4 T. Therefore, available ΔB can be up to 0.8 T. However, a sufficient margin in ΔB is required for half-bridge converters to prevent excessive hysteresis losses and heat generation [19]. Thus, ΔB should be much lower than 0.8 T and the value of ΔB is selected as

| Turn ratio | N_p | N_s | A_{min} [mm ² |
|------------|-------|-------|----------------------------|
| 10 | 30 | 3 | 33 |

 Table 2. Design parameters of transformer

| Table 3. Required v | alues o | of resonant c | components |
|---------------------|---------|---------------|------------|
|---------------------|---------|---------------|------------|

| Specification | Magnetizing inductance | Leakage inductance | Resonant capacitor |
|---------------|---------------------------|--------------------|-----------------------|
| 100 KHz | 280 µH | 80 µH | 18 nF |
| 500 KHz | 70 µH | 10 µH | 6 nF |



Fig. 8. Photo of the transformer for 500 kHz LLC resonant converter: (a) EE core with an air gap to obtain the required magnetizing inductance; (b) Implemented transformer

0.4 T in this paper. Fig. 7 is the calculated result of the variables of N_p and A_{min} for 500 kHz switching frequency. From the calculated results, the proper size of the ferrite core can be chosen, which is not saturated at the switching frequency, with considering the window area of the windings. Table 2 shows the design parameters for the transformer at 500 kHz operation.

3.3 Magnetizing inductance and leakage inductance

Table 3 presents design parameters of the magnetizing and leakage inductances for 100 kHz and 500 kHz switching frequency. To obtain the proper value of the magnetizing inductance, EE cores are used with an air gap as shown in Fig. 8 (a). By adjusting the air gap length, the magnetizing inductance can be obtained as follows:

$$L_m = \frac{N_p^2 \cdot \mu_0 \cdot A_g}{l_g} \tag{12}$$

where l_g is the air gap length and A_g is the cross-sectional area of the center leg.

Generally, the primary and secondary windings of the LLC resonant converter are separated to obtain large and controllable values of the leakage inductance for low switching frequency as shown in Fig. 9 (a) [23]. However, for the high frequency operation such as 500 kHz, the winding structure should be changed because a leakage



Fig. 9. Winding methods for the transformer used in the center-tapped LLC resonant converter: (a) conventional winding method; (b) overlapping winding method to obtain low leakage inductance; (c) bifilar winding method to obtain uniform leakage inductances

inductance in the LLC resonant converter is much smaller than the case of low frequency. In this case, the coupling between the primary and the secondary winding is too small as presented in Table 3. With the conventional winding structure presented in Fig. 9 (a), the leakage inductance will not be small enough.

To obtain the small leakage inductance, the overlapping winding method can be used as shown in Fig. 9 (b). However, applying the overlapping winding may result in an imbalance in the operation of the center-tapped LLC resonant converter, since the distance between the primary winding and the secondary winding 1 is different from the distance between the primary winding 2 [7]. A small difference in the leakage inductances can be negligible at low frequency operation. However, at the high frequency operation, even small difference of the leakage inductances can cause abnormal operations. For example, 7 μ H difference of the leakage inductance has 10% error at 100 kHz operation, while it has 70% error at 500 kHz. To obtain the balance of the leakage inductances in the secondary windings, the bifilar winding method is

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Fig. 10. Measured results of the magnetizing and leakage inductance designed for 500 kHz operation



Fig. 11. Simulation results of 100 kHz and 500 kHz LLC resonant converter

applied as shown in Fig. 9 (c). By wrapping the secondary windings together alternately in the same layer, the leakage inductances of the secondary windings have the same value.

3.4 Measurement Result

Fig. 8 (b) shows an implemented transformer for the 500 kHz prototype converter with considering the calculated design parameters. The conductor of the secondary winding has parallel connections to ensure high output current.

Fig. 10 shows the measured results of the magnetizing and the leakage inductance of the implemented transformer shown in Fig. 8 (b).

The measurement is performed by an impedance analyzer, PSM1735 manufactured by N4L. In Fig. 10, the measured inductances satisfy the required design parameters in Table 3. The measured results show that the implemented transformer can be used in the proposed converter with proper magnetizing leakage inductance at 500 kHz switching frequency.

4. Results

4.1 Simulation results

Fig. 11 shows the simulation results of the 100 kHz and



Fig. 12. Experimental waveforms of 100 kHz LLC resonant converter: (a) 3 A light load case, (b) 10A full load case



Fig. 13. Experimental waveforms of 500 kHz LLC resonant converter: (a) 3 A light load case; (b) 10 A full load case.

500 kHz LLC resonant converter. At the 500 kHz operation, the MOSFET operates under the ZVS condition, and the secondary diode is under a ZCS condition to reduce switching losses. Passive components used in this simulation are the same value shown in Table 3.

4.2 Experimental results

Fig. 12 and 13 show that the 100 kHz and 500 kHz LLC resonant converters operate under the ZVS condition of the



(b)

Fig. 14. Experimental waveforms of 500 kHz output ripple voltage with 1047 μ F capacitor under full load condition: (a) output ripple voltage using 6600 μ F; (b) output ripple voltage using 1047 μ F



Fig. 15. Comparison of output capacitor sizes for 100 kHz and 500 kHz converters

MOSFET, and under the ZCS condition of the secondary diode. Comparing with the simulation results in Fig. 11, there is high frequency ringing in the waveform caused by parasitic capacitance and stray inductance in the practical prototype circuit. In Fig. 14, the output voltage ripple is measured to verify the validity of (6) and Fig. 4. In the case of high capacitance and high ESR condition (6600 µF, 14 m Ω), the output voltage ripple is 1.21 V_{pk pk}. In the case of small ESR and small capacitance condition (1047 µF, 11.66 mΩ), the output voltage ripple is $1.01 V_{pk pk}$. It means that small ESR is more dominant factor to reduce the output voltage ripple than high capacitance at the high switching frequency operation. The volume of the output capacitor is reduced around 5.2 times as shown in Fig. 15. The volume of the transformer is reduced around 1.3 times at the 500 kHz switching frequency as shown in Fig. 16. From those results, the practical size of the output capacitor and the transformer.

Fig. 17 shows measured data of power conversion



Fig. 16. Comparison of 100 kHz and 500 kHz transformer size



Fig. 17. Comparison of power conversion efficiency at 100 kHz and 500 kHz.



Fig. 18. Temperature variations of converters' components according to operating time: (a) 100 kHz case; (b) 500 kHz case.

| Specification | 100 kHz | 500 kHz |
|---------------------|---------|---------|
| Diode | 57 °C | 71 °C |
| MOSFET | 35℃ | 41 °C |
| L6599 (gate driver) | 45 ℃ | 56℃ |
| Transformer | 51 °C | 63 °C |
| Resonant capacitor | 33 °C | 38°C |
| Output capacitor | 31 °C | 34℃ |
| | | |

 Table 4. Comparison of components temperature with respect to the switching frequency

efficiency of the 100 kHz and 500 kHz prototype converters. Maximum efficiency of each switching frequency is 95.9% at the 100 kHz and 94.0% at the 500 kHz, respectively.

At the 500 kHz, the power conversion efficiency is poorer than the case of 100 kHz because of the more power losses caused by the faster switching and the more significant hysteresis effect. Power losses can be indirectly measured using temperature of each component as shown in Fig. 18.

The temperature is measured using ZR-RX25 (OMRON) with an ambient temperature of 20.6 °C. Heat sinks ($25mm \times 16.5mm \times 16mm$) are attached to all the switching components which have temperature variations as increasing the switching frequency. Table 4 shows the temperature variations with respect to the switching frequency. Comparing with the 100 kHz operation, the switching components and the transformer have higher operating temperature. Other passive components also have the temperature increment, however, the difference is smaller than the case of the active and magnetic components.

5. Conclusions

In this paper, the design methodology is proposed for the high switching frequency LLC resonant converter to improve the power density in the practical manner. First, the design of proper magnetizing inductance is suggested to obtain the ZVS condition in the high frequency operation. Second, the design methods of small-sized passive components such as the output capacitor are derived. Third, the optimal transformer design for the high frequency operation is suggested to obtain the desirable inductance values. The proposed methodology and its validity for the high power density are verified using the simulation and the experimental results with 300 W 100 kHz and 500 kHz prototype converters. With the measured temperature and efficiency data, the dominant power losses could be analyzed in the high frequency operation.

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